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Inclosure Material:

Plastic

**Overall Length:** 

0.405 inches

## Terminal Length:

0.135 inches

#### **Overall Height:**

0.250 inches

**Overall Width:** 

0.245 inches

Lens Transparency:

Translucent all light emitting diode

## Function For Which Designed:

### Visible light emitting

End Application:

5895-01-163-1168

### **Component Name And Quantity:**

4 light emitting diode

#### **Mounting Method:**

Terminal

## Semiconductor Material:

Gallium arsenide phosphide all light emitting diode

### Voltage Rating In Volts Per Characteristic:

5.0 forward voltage, dc all light emitting diode

### **Current Rating Per Characteristic:**

40.00 milliamperes source cutoff current preset all light emitting diode

### Color Tone Produced Per Source:

Red lens all light emitting diode

### Luminous Intensity:

3.0 millicandela all light emitting diode

### Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius ambient air

### **Special Features:**

All light emitting diode junction pattern arrangement: pn

### **Terminal Type And Quantity:**

8 pin

# Shelf Life:

N/a

### Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

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